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|  | <p><b>SI7454DP-T1-GE3</b></p>   |
|   | <p><b>Hersteller-Teilenummer:</b> SI7454DP-T1-GE3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 5A PPAK SO-8</p> <p><b>Datenblätter:</b>  <a href="#">SI7454DP-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 3341 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p>                |   |

Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | SI7454DP-T1-GE3   |
| Hersteller                                       | Electro-Films (EFI) / Vishay  |
| Beschreibung                                     | MOSFET N-CH 100V 5A PPAK SO-8   |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> , |
| Teilstatus                                       | 3341 pcs Stock  |
| Hersteller Standard Vorlaufzeit                  | 33 Weeks  |
| detaillierte Beschreibung                        | N-Channel 100V 5A (Ta) 1.9W (Ta) Surface Mount                                    |
| Serie  | TrenchFET®  |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Verpackung / Gehäuse                             | PowerPAK® SO-8  |
| Supplier Device-Gehäuse                          | PowerPAK® SO-8  |
| Verlustleistung (max)                            | 1.9W (Ta)   |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 100V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 5A (Ta)   |
| Rds On (Max) @ Id, Vgs                           | 34 mOhm @ 7.8A, 10V   |
| VGS (th) (Max) @ Id                              | 4V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 30nC @ 10V  |
| Antriebsspannung (Max Rds On, Min Rds On)        | 6V, 10V   |
| Vgs (Max)  | ±20V  |
| Verpackung                                       | Tape & Reel (TR)  |
| Bleifreier Status / RoHS-Status                  | Lead free / RoHS Compliant  |
| Feuchtigkeitsempfindlichkeitsniveau (MSL)        | 1 (Unlimited)   |

SI7454DP-T1-GE3 ist neu im Original, Suche SI7454DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7454DP-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7454DP-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |  |   |   |
|--|--|---|---|
|  <p><b>SI7455DP-T1-GE3</b><br/>Vishay / Siliconix<br/>MOSFET P-CH 80V 28A PPAK SO-8</p> |  <p><b>SI7456CDP-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 100V 27.5A PPAK SO-8</p> |  <p><b>SI7455DP-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 80V 28A PPAK SO-8</p> |  <p><b>SI7455DP-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 80V 28A PPAK SO-8</p> |
|  <p><b>SI7455DP-T1-E3</b><br/>Vishay / Siliconix<br/>MOSFET P-CH 80V 28A PPAK SO-8</p>  |  <p><b>SI7454DP-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 100V 5A PPAK SO-8</p>      |  <p><b>SI7454DP-T1-E3</b><br/>Vishay / Siliconix<br/>MOSFET N-CH 100V 5A PPAK SO-8</p>            |  <p><b>SI7454DP</b><br/>VISHAY<br/>SI7454DP VISHAY</p>   |

heiße Teile

Mehr

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|------------------|------------------|------------------|------------------|------------------|
| SI7447ADP-T1-E3  | SI7447ADP-T1-GE3 | SI7447ADP-T1-GE3 | SI7447DP-T1-GE3  | SI7448DP         |
| SI7448DP-T1-E3   | SI7448DP-T1-E3   | SI7448DP-T1-GE3  | SI7448DP-T1-GE3  | SI7450DP         |
| SI7450DP-T1-E3   | SI7450DP-T1-E3   | SI7450DP-T1-GE3  | SI7450DP-T1-GE3  | SI7452DP-T1-E3   |
| SI7452DP-T1-E3   | SI7452DP-T1-GE3  | SI7452DP-T1-GE3  | SI7454CDP-T1-GE3 | SI7454DP-T1-E3   |
| SI7454DDP-T1-GE3 | SI7454DDP-T1-GE3 | SI7454DP         | SI7454DP-T1-E3   | SI7454DP-T1-E3   |
| SI7454DP-T1-GE3  | SI7456CDP-T1-GE3 | SI7456CDP-T1-GE3 | SI7456DDP-T1-GE3 | SI7456DDP-T1-GE3 |
| SI7456DP         | SI7456DP-T1-E3   | SI7456DP-T1-E3   | SI7456DP-T1-GE3  | SI7456DP-T1-GE3  |
| SI7458DP-T1-E3   | SI7459DP-T1-E3   | SI7459DP-T1-E3   | SI7459DP-T1-GE3  | SI7459DP-T1-GE3  |
| SI7460DP         | SI7460DP-T1-E3   | SI7460DP-T1-E3   | SI7460DP-T1-GE3  | SI7460DP-T1-GE3  |
| SI7461DP-T1-E3   | SI7461DP-T1-E3   | SI7461DP-T1-GE3  | SI7461DP-T1-GE3  | SI7462DP-T1-E3   |

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HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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